OCXO3313C

Very Low Power High Stability Low Phase Noise Miniature OCXO

Features and Benefits

Miniature DIP8 sizes
Very low power consumption(to 130mW at +25°C)
High frequency stability(less than±5ppb over -40°C to +85°C)
Very fast warming-up (up to 30s)
Very low phase-noise level (-172dBc/Hz, floor)
Low aging (to 0.1ppb/day, 0.15ppm/year)
Fundamental operation at up to 150MHz

Typical Applications

Portable Wireless Communications Mobile Test Equipment Beacons and Rescue Systems Battery Powered Applications

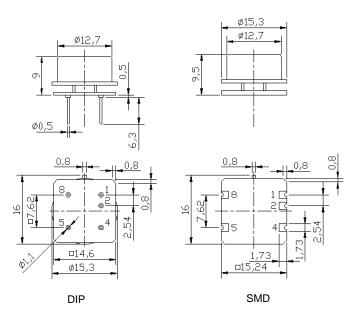
Description

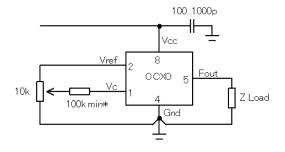
The crystal plate inside the TO-8 vacuum holder. Such approach results in radical reduction of the OCXO sizes, power consumption and warm-up time. In spite of very small sizes and extremely low power consumption these oscillators exhibit excellent frequency stability and low phase-noise level comparable with that of the high-end conventional OCXO designs. The OCXO3313C models have DIP8 compatible sizes and pins-out and are among the world smallest high stability OCXOs.

Mechanical Drawing & Pin Connections

Drawing No:

MD140077-4





Pin	Signal
1	Electrical tuning
2	Reference voltage
4	GND
5	RF Out
8	+V Supply

Unit in mm

1mm = 0.0394 inches



Dynamic Engineers Inc.

2550 Gray Falls Dr., Suite#128, Houston, TX, 77077 USA TEL: 1-281-870-8822 EMAIL: Sales@DynamicEng.com

OCXO3313C

Very Low Power High Stability Low Phase Noise Miniature OCXO

Specifications

	Oscillator	Sym	Condition		Value		Unit	Note
Specification		Ť	Condition	Min.	Тур.	Max.	Offic	Note
Operation	al Frequency	f_0		8		150	MHz	
Initial Tole	erance	$(f-f_0)/f_0$	+25°C, V _C =0.5*V _{ref}		±0.1		ppm	
RF Outpu	it							
	Level	L	V _{CC} =5V	+7			dBm	
Sine-			Vcc=3.3V	+4				
wave	Load Harmonics Level	R _L			50	-25	Ohm dBc	
Sub-harm	II.				None	-25	ubc	+
Jub-Hallil				10	INOITE		Kohm	
	Load			10		15/5	pF	10/100MHz
HCMOS	High Level Voltage	V _H	Vcc=5V	3.8			V	
(TTL)	0		Vcc=3.3V	2.4			-	
(· · = /	Low Level Voltage	V_L		45		0.4	V	
	Duty Cycle			45		55	%	40/400141-
D 0.	Rise/Fall Time					10/3	ns	10/100MHz
Power Su	ірріу	1	T	4.75	F 0	5.05		
Voltage		V_{cc}		4.75 3.15	5.0 3.3	5.25 3.45	V	
			Warm-up	3.13	3.3	1200		10MHz,
Power Co	nsumption		Steady-state, +25°C	130	180	1200	mW	-40° C to +85° C
			At+25° C to Δf/f=1e-8	130	120			ref. frequency after
Warm-up	Time:	T_{up}	At+25° C to $\Delta f/f=1e-7$	30	60		S	15 min work.
Frequenc	v Control		7 tt 20 0 to 201 10 1	33				To Time Works
•	•	١,,	V _{cc} =5V	0		4.3	.,	
Control Vo	oltage Range	V _c	Vcc=3.3V	0		2.8	V	
Tuning Ra	ngo		Compliance with	±0.3	±1.0		nnm	Positive slope
Turning Ka	inge		10 years of aging				ppm	Positive slope
Reference	Voltage Output	V_{ref}		4.1	4.2	4.4	V	
		- 161		2.7	2.8	2.9	•	
	y Stability emperature	T	ref 25°C		ı	T T	nnh	Coo ordering code
	inperature ipply Voltage		Ref V _{CC} typ.	±5	±2		ppb ppb	See ordering code
Versus Ac			Worst direction	±0.3	±2 ±1.0		ppb/G	
Retrace	Celeration		24h work after 24h off	±0.5	±1.0	±10	ppb/C	10MHz
	Per day			±0.1		±10	ppb	10MHz
Aging	First Year		After 30 days of operation	±0.15			ppm	See ordering code
			1Hz	-105/		-90/		1
			10 Hz	-135/-100		-120/-90		
CCD Dbas	a Maiaa		100 Hz	-155/-130		-145/-120		
SSB Phas	se inoise		1 KHz	-165/-155		-155/-150	dBc/Hz	10MHz/100MHz
			10 KHz	-170/-170		-165/-165		
			100 KHz	-172/-172		-165/-165		
Allan Vari			1s	5		40	e-12	10MHz
	ental Conditions							
	temperature range		-40°C to +85°C(See ordering of	ode)				
	emperature range		-60°C to +85 °C					
Power Voltage		-0.5V to V _{CC} +20%						
Control Voltage		-0.5V to +6V						
Humidity		Non-condensing 95%						
Mechanical Shock		Per MIL-STD-202, 30G half sine pulse, 11ms						
			Per MIL-STD-202, 10G swept sine 10 to 2000 Hz					
Solderability		Hand solder only – not reflow compatible 260°C 10s (on pins)						
Soldering Condition Washing with water or alcohol based detergent allowed only with final enough drying stage			ying stage					



OCXO3313C

Very Low Power High Stability Low Phase Noise Miniature OCXO

Ordering Information

OCXO3313C - xxMHz - 01 02 03 04 05 06

Group Code

For example, OCXO3313C- -100MHz-247111 denotes the OCXO has the following specifications:

Frequency 100MHz

Temperature Range -10°C to +60°C

Stability Over Temperature ±10ppb

Aging per day / year 2ppb / 0.2ppm Supply Voltage 3.3V ±10% Utput HCMOS Package DIP

01	Temperature Range
Code	Specification
1	0°C+50°C
2	-10°C+60°C
3	0°C+70°C
4	-20°C+70°C
5	-30°C+70°C
6	-40°C+85°C
7	-55°C+85°C
8	-60°C+85°C

02	Stability Over Temperature			
		Avai	lable	
Code	Specification	temperature range		
		code		
		10MHz	100MHz	
1	±2.0 ppb	1 to 2	-	
2	±3.0 ppb	1 to 5	-	
3	±5.0 ppb	1 to 6	-	
4	±10 ppb	1 to 8	1 to 2	
5	±20 ppb	1 to 8	1 to 5	
6	±30 ppb	1 to 8	1 to 6	
7	±50 ppb	1 to 8	1 to 7	
8	±100 ppb	1 to 8	1 to 8	

03	Aging per day/year, ppb/ppm		
Code	Specification		
1	0.1/0.015		
2	0.2/0.02	≤10MHz	
3	0.3/0.03		
4	0.5/0.05	≤20MHz	
5	1/0.1	≤40MHz	
6	1.5/0.15	≤50MHz	
7	2/0.2	≤120MHz	
8	3/0.3	≤120MHz	
9	5/0.5	≤150MHz	

04	Supply Voltage
Code	Specification
1	3.3V±5%
2	5.0V±5%

05	RF Output
Code	Specification
1	HCMOS
2	Sine-wave

06	Packaging
Code	Specification
1	DIP
2	SMD